

Medium power transistor (60V, 0.5A)

2SC5876

●Features

- 1) High speed switching. (Tf : Typ. : 80ns at Ic = 500mA)
- 2) Low saturation voltage, typically
(Typ. : 150mV at Ic = 100mA, Ib = 10mA)
- 3) Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SA2088

●Applications

Small signal low frequency amplifier
High speed switching

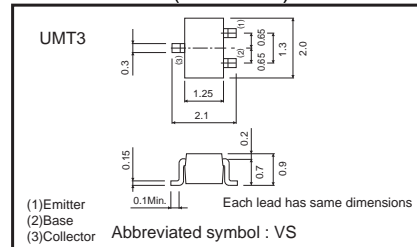
●Structure

NPN Silicon epitaxial planar transistor

●Packaging specifications

Type	Package	Taping
	Code	T106
	Basic ordering unit (pieces)	3000
2SC5876		○

●Dimensions (Unit : mm)



●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V _{CB0}	60	V
Collector-emitter voltage	V _{CE0}	60	V
Emitter-base voltage	V _{EB0}	6	V
Collector current	I _c	0.5	A
	I _{cP}	1.0	A *1
Power dissipation	P _c	200	mW *2
Junction temperature	T _j	150	°C
Range of storage temperature	T _{stg}	-55 to +150	°C

*1 Pw=10ms

*2 Each terminal mounted on a recommended land.

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV _{CB0}	60	–	–	V	I _C =100μA
Collector-emitter breakdown voltage	BV _{CEO}	60	–	–	V	I _C =1mA
Emitter-base breakdown voltage	BV _{EBO}	6	–	–	V	I _E =100μA
Collector cut-off current	I _{CB0}	–	–	1.0	μA	V _{CB} =40V
Emitter cut-off current	I _{EBO}	–	–	1.0	μA	V _{EB} =4V
Collector-emitter saturation voltage	V _{CE(sat)}	–	150	300	mV	I _C =100mA, I _B =10mA
DC current gain	h _{FE}	120	–	390	–	V _{CE} =2V, I _C =50mA
Transition frequency	f _T	–	300	–	MHz	V _{CE} =10V, I _E =–100mA, f=10MHz *1
Collector output capacitance	C _{ob}	–	5	–	pF	V _{CB} =10V, I _E =0mA, f=1MHz
Turn-on time	t _{on}	–	70	–	ns	I _C =500mA, I _{B1} =50mA
Storage time	t _{stg}	–	130	–	ns	I _{B2} =–50mA
Fall time	t _f	–	80	–	ns	V _{CC} =25V *1

*1 Pulse measurement

●hFE RANK

Q	R
120-270	180-390

●Electrical characteristic curves

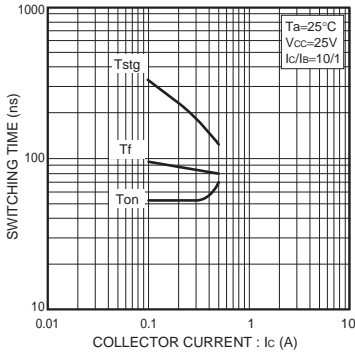


Fig.1 Switching Time

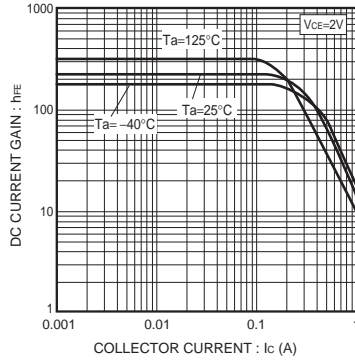


Fig.2 DC current gain vs. collector current

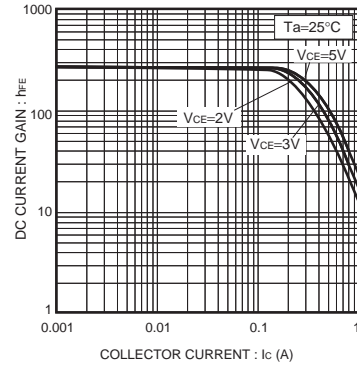


Fig.3 DC current gain vs. collector current

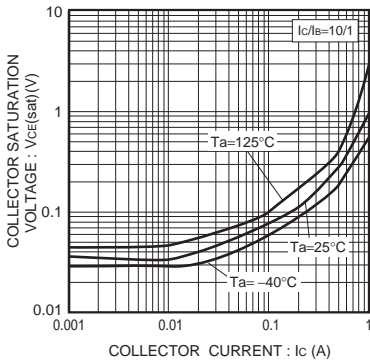


Fig.4 Collector-emitter saturation voltage vs. collector current

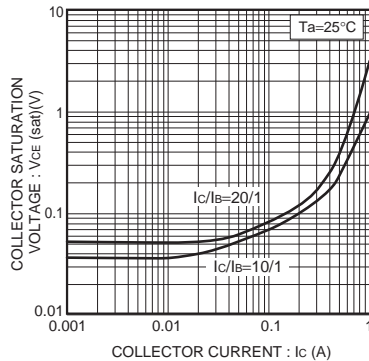


Fig.5 Collector-emitter saturation voltage vs. collector current

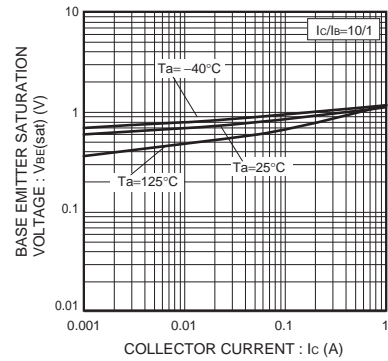


Fig.6 Base-emitter saturation voltage vs. collector current

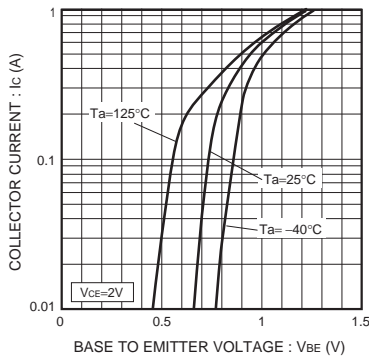


Fig.7 Ground emitter propagation characteristics

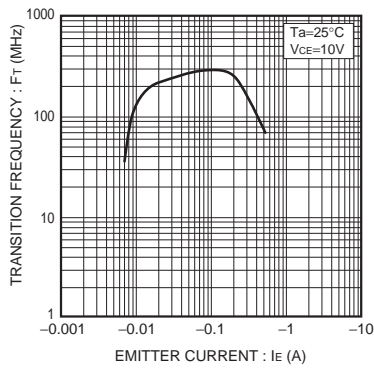


Fig.8 Transition frequency

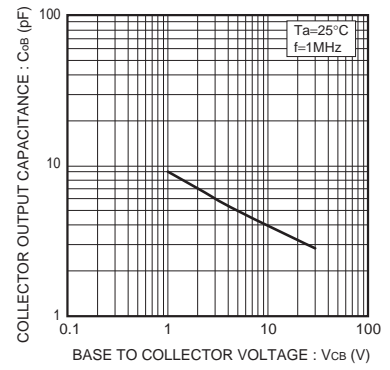
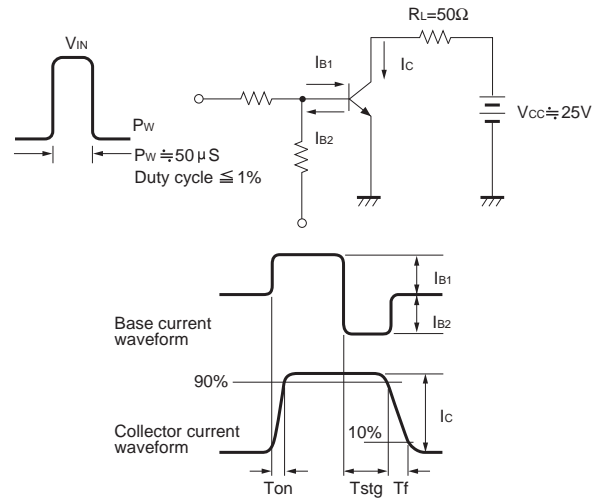


Fig.9 Collector output capacitance

●Switching characteristics measurement circuits



Notes

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